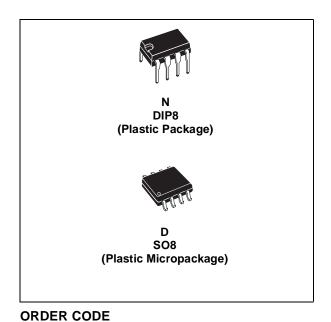


TL071 TL071A - TL071B

LOW NOISE J-FET SINGLE OPERATIONAL AMPLIFIERS

- \blacksquare WIDE COMMON-MODE (UP TO V_{CC}^+) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- LOW NOISE $e_n = 15 \text{nV}/\sqrt{\text{Hz}}$ (typ)
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- LOW HARMONIC DISTORTION : 0.01% (typ)
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE: 16V/µs (typ)



DESCRIPTION

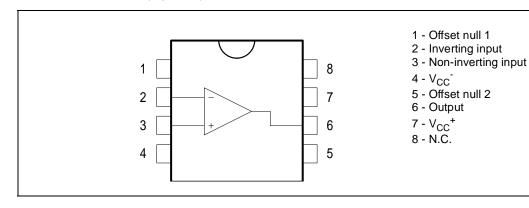
The TL071, TL071A and TL071B are high speed J-FET input single operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

Part Number	Temperature Range	Package					
Fait Number	Temperature Nange	N	D				
TL071M/AM/BM	-55°C, +125°C	•	•				
TL071I/AI/BI	-40°C, +105°C	•	•				
TL071C/AC/BC	0°C, +70°C	•	•				
Example: TL071CN							

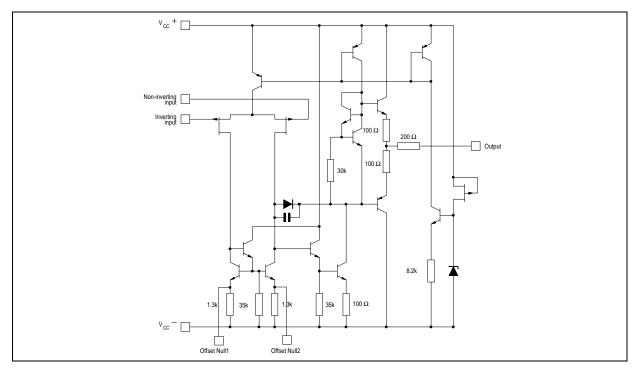
N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

PIN CONNECTIONS (top view)

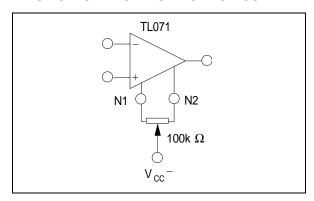


March 2001 1/10

SCHEMATIC DIAGRAM



INPUT OFFSET VOLTAGE NULL CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TL071M, AM, BM	TL071I, AI, BI	TL071C, AC, BC	Unit	
V _{CC}	Supply voltage - note 1)	±18				
V _i	Input Voltage - note ²⁾	±15				
V _{id}	Differential Input Voltage - note 3)	±30				
P _{tot}	Power Dissipation	680				
	Output Short-circuit Duration - note 4)	Infinite				
T _{oper}	Operating Free-air Temperature Range	-55 to +125 -40 to +105 0 to +70		°C		
T _{stg}	Storage Temperature Range	-65 to +150				

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}.
- The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating
 is not exceeded

ELECTRICAL CHARACTERISTICS

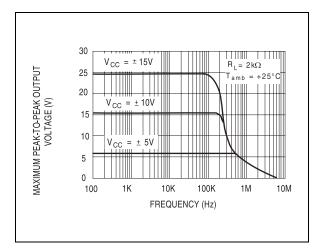
 $V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter		TL071I,M,AC,AI,AM, BC,BI,BM			TL071C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V _{io}	Input Offset Voltage (R_s = 50 Ω) T_{amb} = +25°C $TL071$ $TL071A$ $TL071B$ $T_{min} \le T_{amb} \le T_{max}$ $TL071$ $TL071A$ $TL071B$		3 3 1	10 6 3 13 7 5		3	10	mV
DV _{io}	Input Offset Voltage Drift		10			10		μV/°C
l _{io}	Input Offset Current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	100 4		5	100 10	pA nA
l _{ib}	Input Bias Current -note $^{1)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		20	200 20		20	200 20	pA nA
A _{vd}	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I _{CC}	Supply Current, no load $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V _{icm}	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
l _{os}	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
±V _{opp}	$\begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = +25^{\circ}\text{C} & \text{RL} = 2k\Omega \\ \text{RL} = 10k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & \text{RL} = 2k\Omega \\ \text{RL} = 10k\Omega \end{array}$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate (T_{amb} = +25°C) V_{in} = 10V, R_L = 2k Ω , C_L = 100pF, unity gain	8	16		8	16		V/µs
t _r	Rise Time (T_{amb} = +25°C) V_{in} = 20mV, R_L = 2k Ω , C_L = 100pF, unity gain		0.1			0.1		μs
K _{ov}	Overshoot (T_{amb} = +25°C) V_{in} = 20mV, R_L = 2k Ω , C_L = 100pF, unity gain		10			10		%
GBP	Gain Bandwidth Product (T_{amb} = +25°C) V_{in} = 10mV, R_L = 2k Ω , C_L = 100pF, f= 100kHz	2.5	4		2.5	4		MHz
R _i	Input Resistance		10 ¹²			10 ¹²		Ω

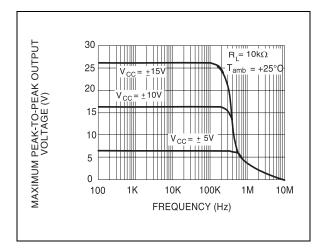
Symbol	Parameter		TL071I,M,AC,AI,AM, BC,BI,BM			TL071C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
THD	Total Harmonic Distortion (T_{amb} = +25°C, f= 1kHz, R _L = 2k Ω ,C _L = 100pF, A _v = 20dB, V _o = 2V _{pp})		0.01			0.01		%
e _n	Equivalent Input Noise Voltage $R_S = 100\Omega$, $f = 1KHz$		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase Margin		45			45		degrees

^{1.} The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

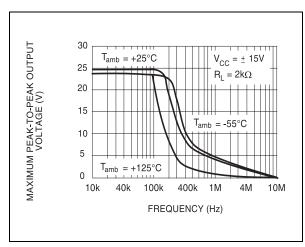
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



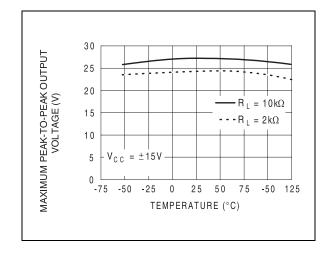
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



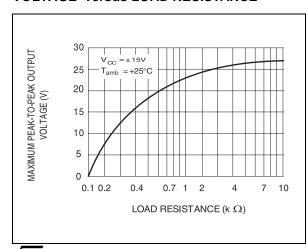
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



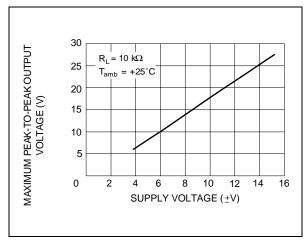
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.



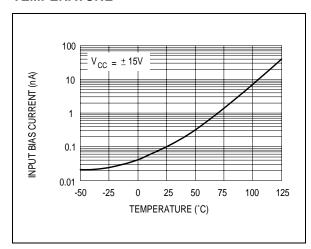
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



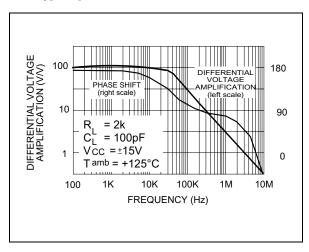
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE



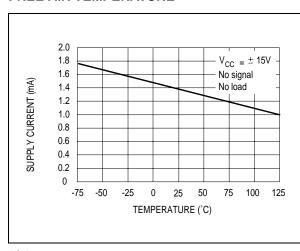
INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



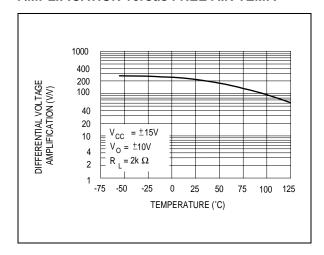
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



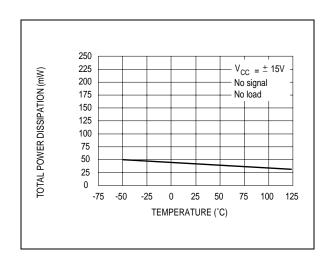
SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



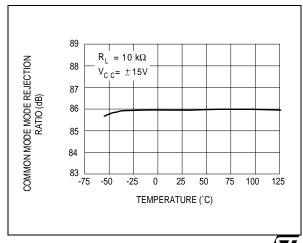
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.



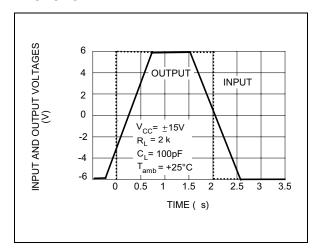
TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



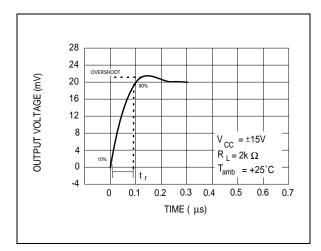
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



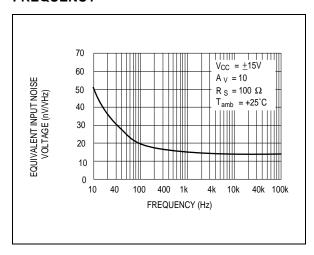
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



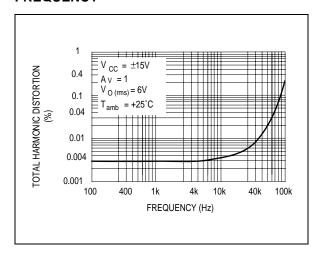
OUTPUT VOLTAGE versus ELAPSED TIME



EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



TOTAL HARMONIC DISTORTION versus FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

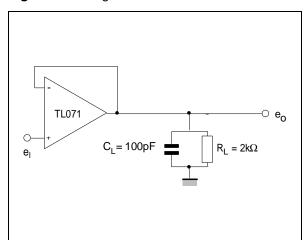
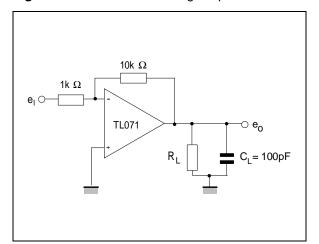
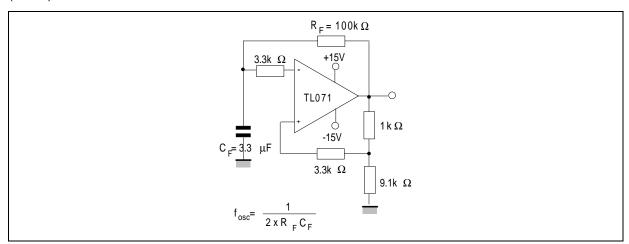


Figure 2 : Gain-of-10 Inverting Amplifier

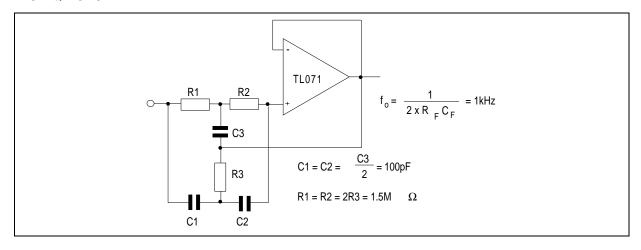


TYPICAL APPLICATIONS

(0.5Hz) SQUARE WAVE OSCILLATOR

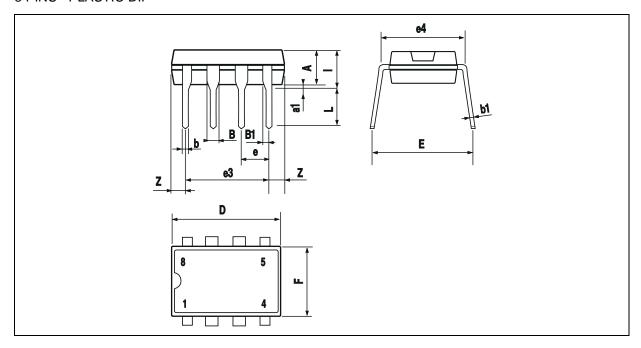


HIGH Q NOTCH FILTER



PACKAGE MECHANICAL DATA

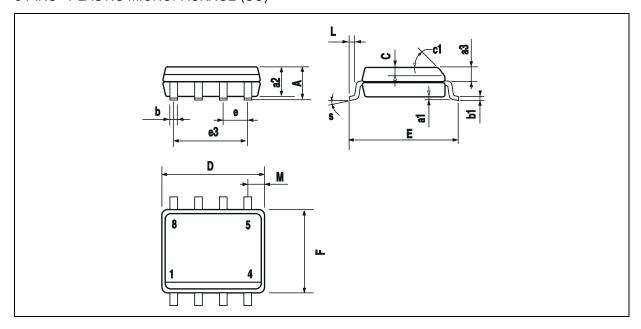
8 PINS - PLASTIC DIP



Dim.		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А		3.32			0.131			
a1	0.51			0.020				
В	1.15		1.65	0.045		0.065		
b	0.356		0.55	0.014		0.022		
b1	0.204		0.304	0.008		0.012		
D			10.92			0.430		
Е	7.95		9.75	0.313		0.384		
е		2.54			0.100			
e3		7.62			0.300			
e4		7.62			0.300			
F			6.6			0260		
i			5.08			0.200		
L	3.18		3.81	0.125		0.150		
Z			1.52			0.060		

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.75			0.069		
a1	0.1		0.25	0.004		0.010		
a2			1.65			0.065		
а3	0.65		0.85	0.026		0.033		
b	0.35		0.48	0.014		0.019		
b1	0.19		0.25	0.007		0.010		
С	0.25		0.5	0.010		0.020		
c1			45°	(typ.)				
D	4.8		5.0	0.189		0.197		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		3.81			0.150			
F	3.8		4.0	0.150		0.157		
L	0.4		1.27	0.016		0.050		
М			0.6			0.024		
S	8° (max.)							

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